

# RD3ST24

## Standby Control IC

REJ03D0521-0200 Rev.2.00 Mar 01, 2006

#### **Description**

RD3ST24 is including the standby control circuit for a microcomputer in 8 pin packages.

When MSTB input "Low", SWOUT output "Low", STBYOUT output become "High" and cancels standby condition.

And  $\overline{RESOUT}$  output becomes "High" after it passed period (t1\*) when it is stable the oscillation that was set up with RC bill outside and cancel the reset condition of a microcomputer.

Also when MSTB input "Low", RESOUT output becomes "Low" and makes reset condition.

After the delay time (t2) of prescription passed subsequently, SWOUT output "High" STBYOUT output becomes "Low" and makes a microcomputer standby condition.

\*: t1 = K•RC (K is coefficient: Reference of application data)

#### **Features**

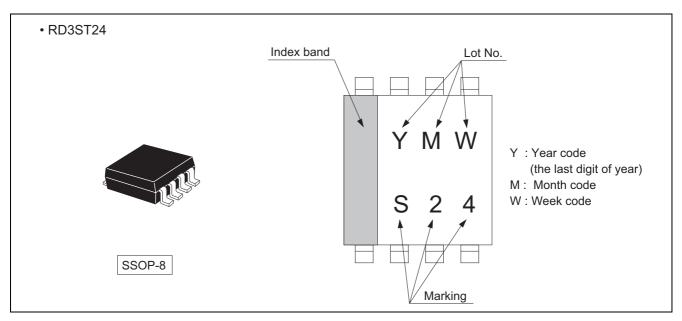
Supply voltage range: 2.3 to 5.5 V
Temperature range: -40 to +85°C

• Output current:  $\pm 6$ mA (@V<sub>CC</sub>=3.0V),  $\pm 12$ mA (@Vcc=4.5V)

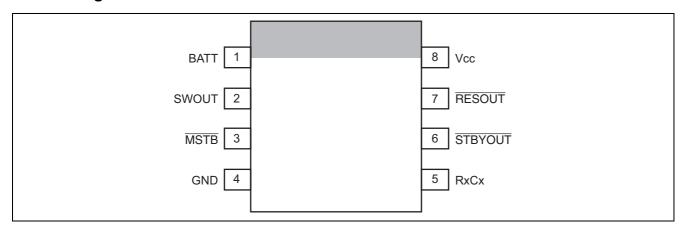
• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD3ST24USE	SSOP-8 pin	PVSP0008KA-A (TTP-8DBV)	US	E (3,000 pcs/reel)

#### **Outline and Article Indication**



## **Pin Arrangement**



## **Pin Description**

Symbol	Pin Name
BATT	The battery power supply
SWOUT	Output for Power MOS FET control
MSTB	Manual standby Input
GND	Ground
$R_xC_x$	Terminal for external resistance and capacitance
STBYOUT	Standby Output
RESOUT	Reset Output
V <sub>CC</sub>	Power supply

## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to V <sub>CC</sub> + 0.5	V	
Output voltage range *1,2	Vo	-0.5 to V <sub>CC</sub> + 0.5	V	Output: H or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	±20	mA	V <sub>1</sub> < 0
Output clamp current	lok	±50	mA	$V_0 < 0$ or $V_0 > V_{CC}$
Continuous output current	Io	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through Vcc or GND	Icc or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 6.0 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

### **Recommended Operating Conditions**

Item	Symbol	Min	Тур	Max	Unit	Conditions
Supply voltage range	V <sub>CC</sub> , BATT	2.3	_	5.5	V	
Input voltage range	Vı	0.0	_	Vcc	V	
Output voltage range	Vo	0.0	_	5.5	V	
Output current	Іон	-	_	-6	mA	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$
		_	_	-12		V <sub>CC</sub> = 4.5 V to 5.5 V
	I <sub>OL</sub>	-	_	6		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$
		-	_	12		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$
External resistance	R <sub>X</sub>	1.0	_	_	kΩ	
External capacitance	C <sub>X</sub>	_	Unlimited	_	F	
Operating free-air temperature	Та	-40	_	85	°C	

### **Electrical Characteristic**

Ta = -40 to  $85^{\circ}C$ 

Item	Symbol	V <sub>CC</sub> (V)	BATT (V)	Min	Тур	Max	Unit	Test condition
Input voltage V <sub>IH</sub>		2.5±0.2		0.7×V <sub>CC</sub>	_	_	V	
		3.3±0.3		0.7×V <sub>CC</sub>	_	_		
		5.0:	±0.5	0.7×V <sub>CC</sub>	_	_		
	V <sub>IL</sub>	2.5	±0.2	_	_	0.3×V <sub>CC</sub>	V	
		3.3	±0.3	_	_	0.3×V <sub>CC</sub>		
		5.0:	±0.5	_	_	0.3×V <sub>CC</sub>		
Output voltage	V <sub>OH</sub>	3.0	3.0	2.9	_	_	V	I <sub>OH</sub> =-100μA
				2.48	_	_		I <sub>OH</sub> =–6mA
		4.5	4.5	4.4	_			I <sub>OH</sub> =-100μA
				3.8	_	_		I <sub>OH</sub> =-12mA
	$V_{OL}$	3.0	3.0	_	_	0.1	V	I <sub>OL</sub> =100μA
				_	_	0.44		I <sub>OL</sub> =6mA
		4.5	4.5	_	_	0.1		I <sub>OL</sub> =100μA
				_	_	0.55		I <sub>OL</sub> =12mA
Input current	I <sub>IN</sub>	5.5	5.5	_	_	±10	μΑ	V <sub>IN</sub> =0V or V <sub>CC</sub> , R <sub>X</sub> C <sub>X</sub> =GND
Output leakage current	l <sub>OFF</sub>	0	0	_	_	±10	μΑ	V <sub>O</sub> =5.5V, R <sub>X</sub> C <sub>X</sub> =GND (RESOUT, STBYOUT, SWOUT)
Quiescent	Icc	5.5	5.5	_		±10	μΑ	V <sub>IN</sub> =0V or V <sub>CC</sub> , R <sub>X</sub> C <sub>X</sub> =GND
supply current	I <sub>CC (BATT)</sub>	5.5	5.5	_		±10	uA	
		0	5.5	_	_	±10	uA	

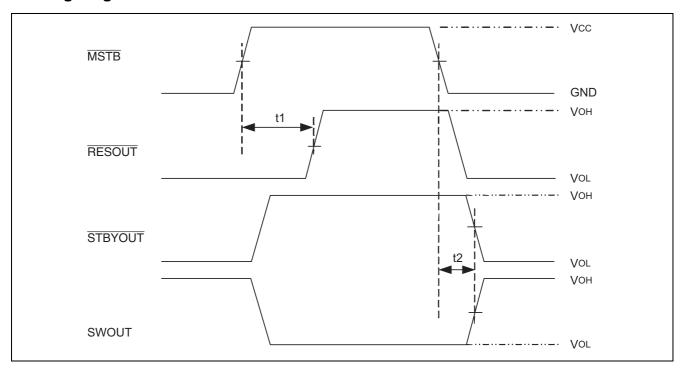
## **Switching Characteristics**

Ta = -40 to  $85^{\circ}C$ 

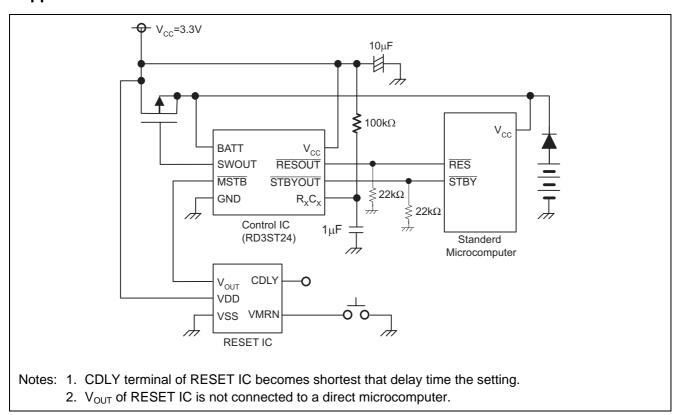
Item	Symbol	V <sub>CC</sub> (V) *1	BATT (V)	Min	Тур	Max	Unit	Test condition
Propagation	t1	3.3	3.3	80	95	110	μs	$R_X=10k\Omega$ , $C_X=0.01\mu F$
delay time				0.8	0.95	1.1	ms	$R_X=10k\Omega$ , $C_X=0.1\mu F$
				80	95	110	ms	$R_X=100k\Omega$ , $C_X=1.0\mu F$
		5.0	5.0	80	95	110	μs	$R_X=10k\Omega$ , $C_X=0.01\mu F$
				0.8	0.95	1.1	ms	$R_X=10k\Omega$ , $C_X=0.1\mu F$
				80	95	110	ms	$R_X=100k\Omega$ , $C_X=1.0\mu F$
	t2	3.3	3.3	125	_	250	ns	
		5.0	5.0	70	_	160	ns	

Note: 1. Ta = 25°C

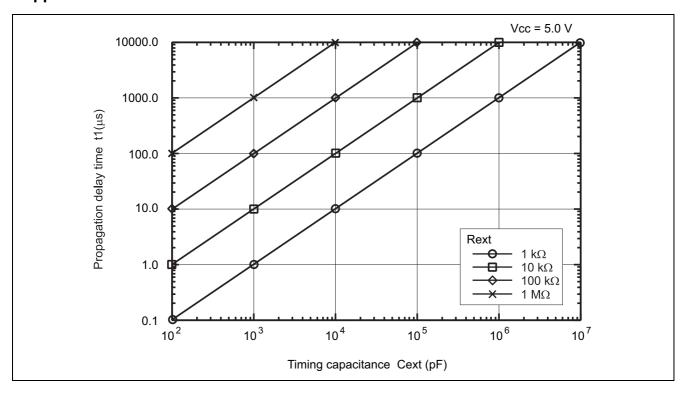
## **Timing Diagram**

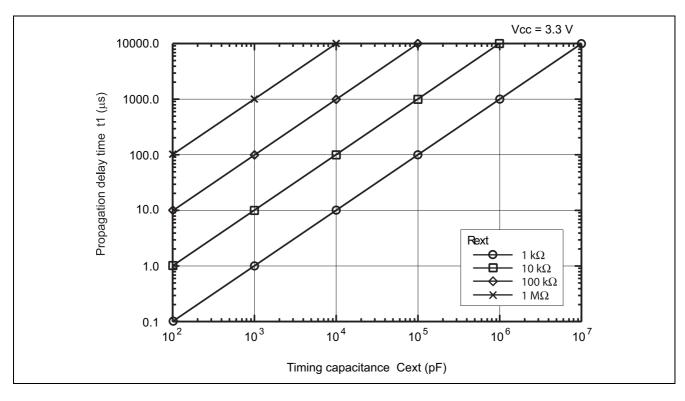


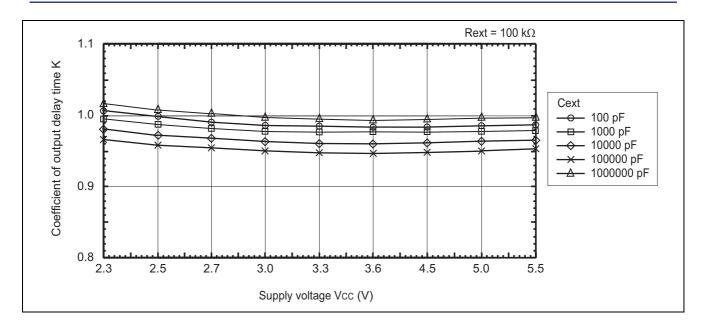
## **Application Circuit**

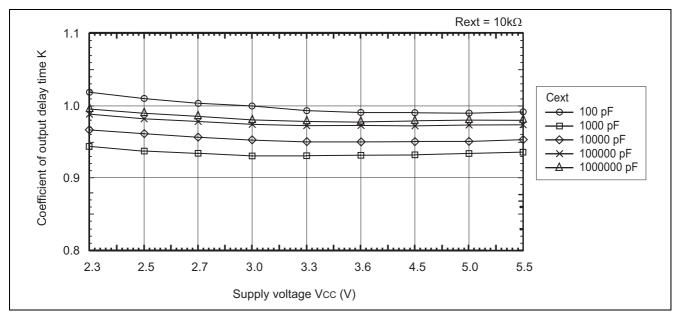


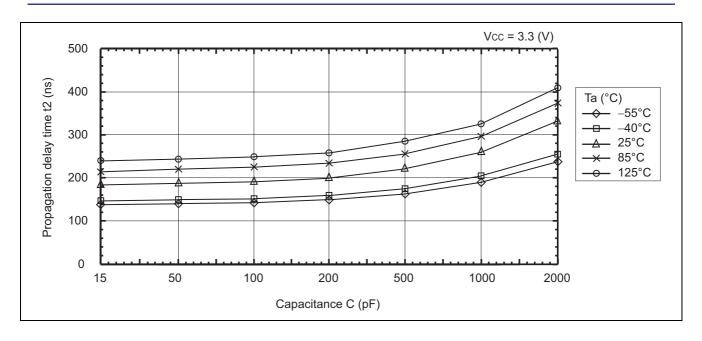
## **Application Data**

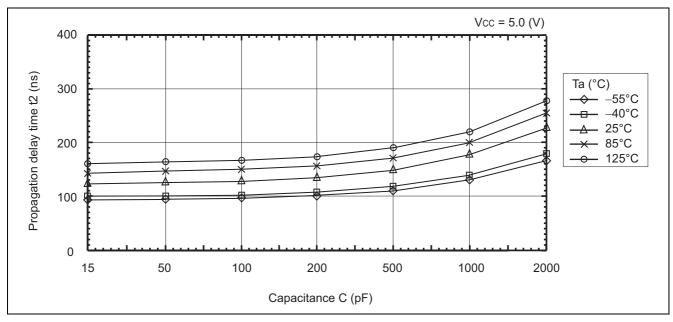




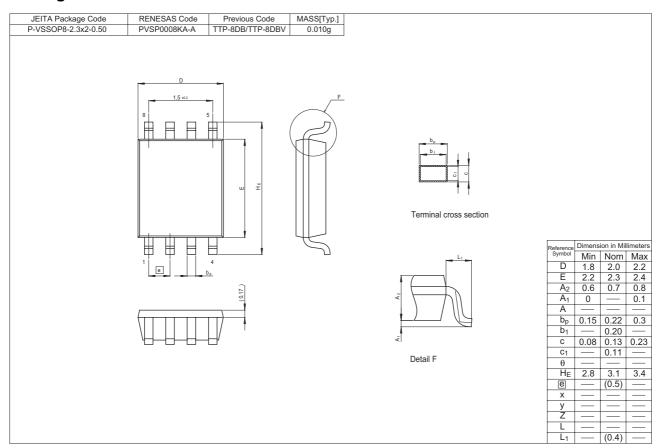








## **Package Dimensions**



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